

# Columbia University Optics and Quantum Electronics Seminar



## “Graphene electronics, Optoelectronics and Plasmonics”



**Dr. Tony Low**

*IBM TJ Watson; Nanoscale Science and Technology Group*

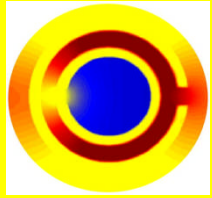
**Date/Time:** Monday, September 30, 11 – 12 noon

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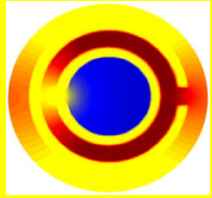
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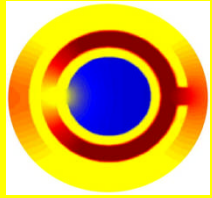
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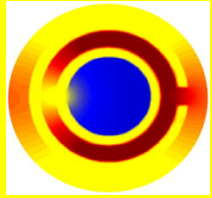
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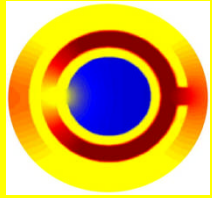
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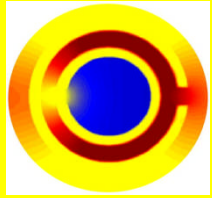
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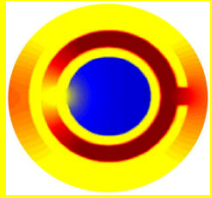
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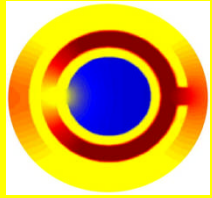
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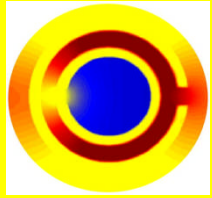
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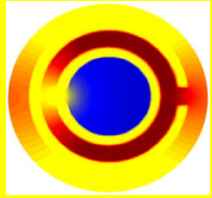
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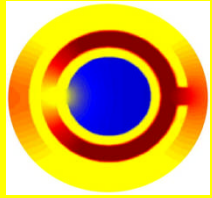
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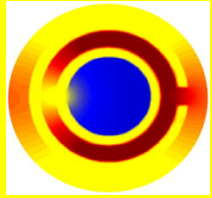
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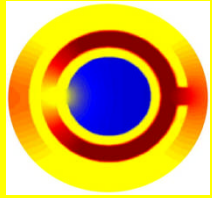
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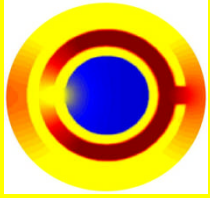
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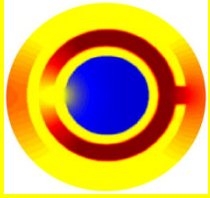
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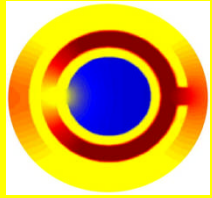
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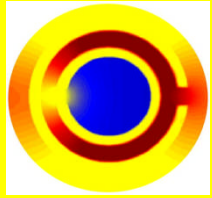
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# Columbia University Optics and Quantum Electronics Seminar



## “Graphene electronics, Optoelectronics and Plasmonics”



**Dr. Tony Low**

*IBM TJ Watson; Nanoscale Science and Technology Group*

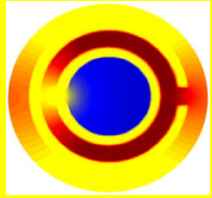
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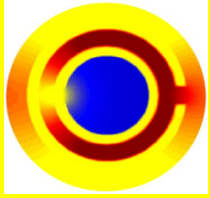
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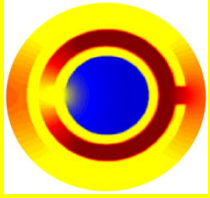
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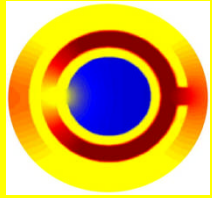
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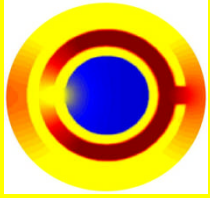
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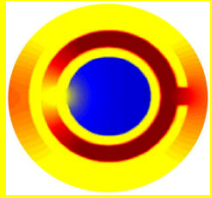
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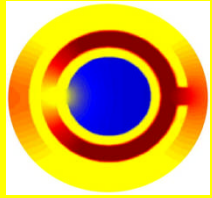
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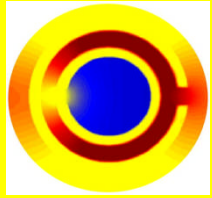
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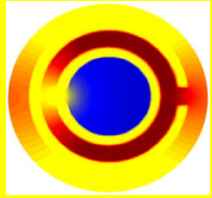
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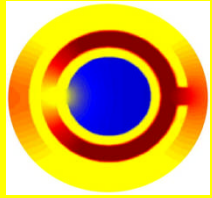
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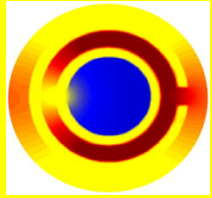
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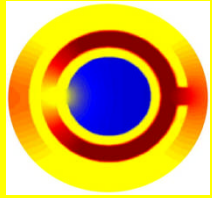
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